

## FF107M SURFACE MOUNT FAST RECOVERY RECTIFIER

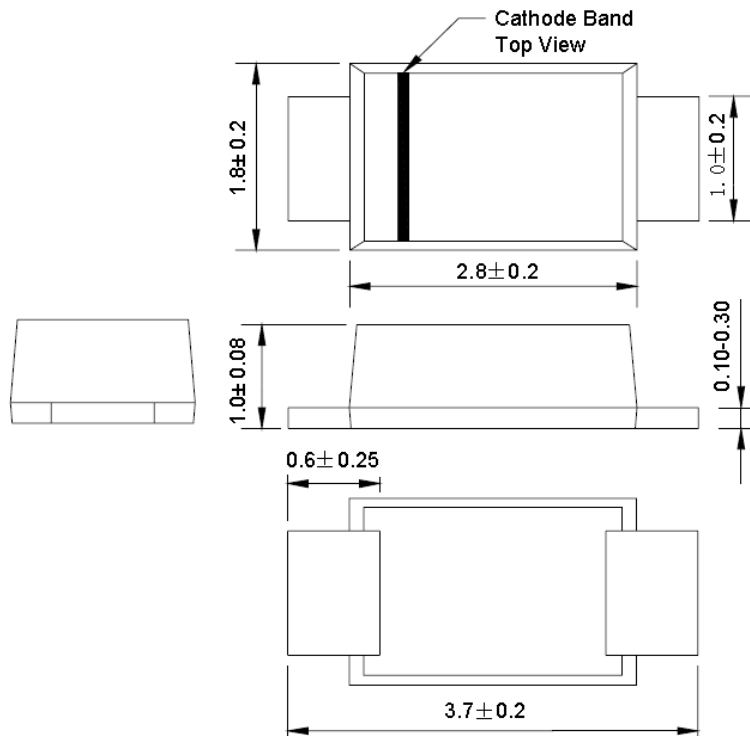
### Features:

- Glass passivated device
- Ideal for surface mounted applications
- Low reverse leakage
- Metallurgically bonded construction
- High temperature soldering guaranteed: 250 C/10 seconds, 0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension
- Glass passivated chip junction
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Mechanical Data:

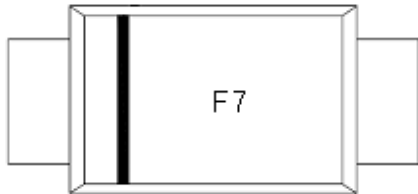
- Case: JEDEC SOD-123SL molded plastic body over passivated chip
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.0007 ounce, 0.02 grams

### Mechanical Dimensions: In mm



**SOD-123SL**

**Marking Diagram:**



F7 = Part Number

**Cautions:** Molding resin  
 Epoxy resin UL:94V-0

**Ordering Information:**

Device	Package	Shipping
FF107M	SOD-123SL (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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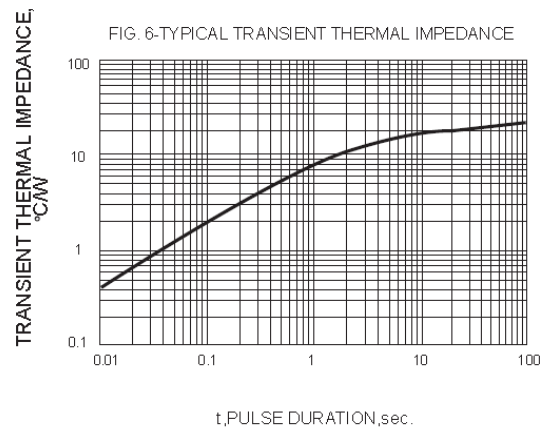
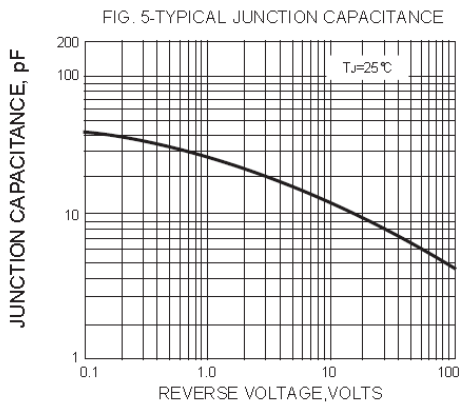
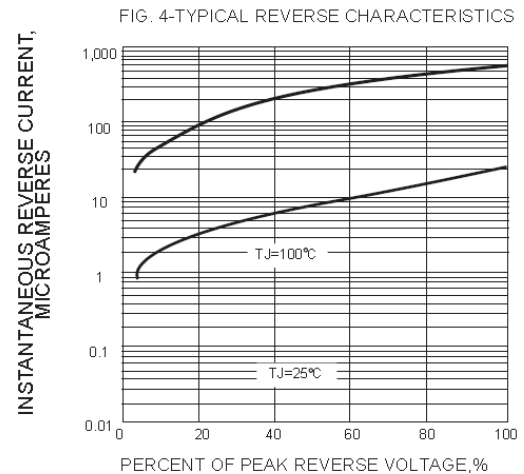
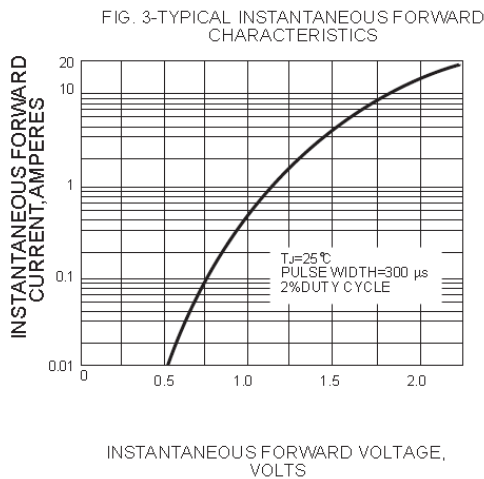
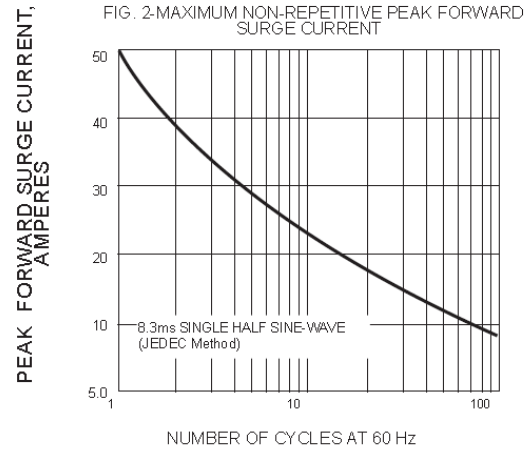
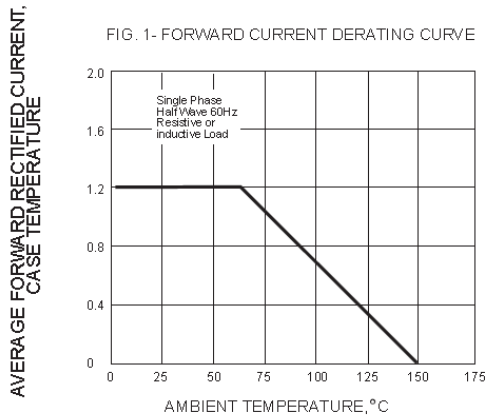
**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**


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Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	FFM107	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	1000	VOLTS
Maximum average forward rectified current at $T_A=65^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	1.2	Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) $T_L=25^\circ\text{C}$	$I_{FSM}$	50.0	Amps
Maximum instantaneous forward voltage at 1.2A	$V_F$	1.3	Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	5.0 50.0	$\mu\text{A}$
Maximum reverse recovery time (NOTE 2)	$t_{rr}$	250	ns
Typical junction capacitance (NOTE 3)	$C_J$	15	pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0	$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

Note: 1. Averaged over any 20ms period.  
 2. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .  
 3. Measured at 1MHz and applied reverse voltage of 4.0V D.C.



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